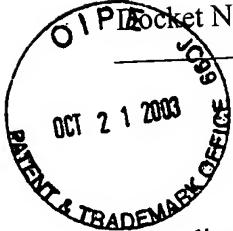


Docket No.: ASMEX.320A



INFORMATION DISCLOSURE STATEMENT

Applicant : Pomerade et al.
 App. No. : 10/074,722
 Filed : February 11, 2002
 For : INTEGRATION OF HIGH K GATE
 DIELECTRIC
 Examiner : Ron Everett Pompey
 Group Art Unit : 2812

Commissioner for Patents
 P.O. Box 1450
 Alexandria, VA 22313-1450

Dear Sir:

Enclosed is form PTO-1449 listing seven (7) references that are also enclosed.

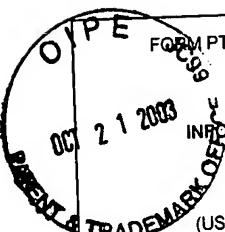
This Information Disclosure Statement is being filed under 37 C.F.R. § 1.97(c)(2) before the mailing date of a final action and before the mailing of a Notice of Allowance. This Statement is accompanied by the fees set forth in 37 C.F.R. § 1.17(p). The Commissioner is hereby authorized to charge any additional fees which may be required or to credit any overpayment to Account No. 11-1410.

Respectfully submitted,
 KNOBBE, MARTENS, OLSON & BEAR, LLP

Dated: 10/16/03

10/24/2003 REMBRANDT 00000037 10074722
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By: Joseph J. Mallon
 Joseph J. Mallon
 Registration No. 39,287
 Attorney of Record
 Customer No. 20,995
 (619) 235-8550



P E FORM PTO-1449 U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE <i>21 2003</i> INFORMATION DISCLOSURE STATEMENT BY APPLICANT TRADEMARK OFFICE (USE SEVERAL SHEETS IF NECESSARY)	ATTY. DOCKET NO. ASMEX.320A	APPLICATION NO. 10/074,722
	APPLICANT Pomerade et al.	
	FILING DATE February 11, 2002	GROUP 2812

U.S. PATENT DOCUMENTS

FOREIGN PATENT DOCUMENTS

OTHER DOCUMENTS (INCLUDING AUTHOR, TITLE, DATE, PERTINENT PAGES, ETC.)

EXAMINER INITIAL	OTHER DOCUMENTS (INCLUDING AUTHOR, TITLE, DATE, PERTINENT PAGES, ETC.)
7.	Ikoma et al., Growth of Si/3C-SiC/Si(100) heterostructures by pulsed supersonic free jets, Applied Physics Letters, Volume 75, No. 25, Pp. 3977-3979, December 1999

S:\DOCS\JOM\JOM-5360.DOC:101503

EXAMINER _____ **DATE CONSIDERED** _____
*EXAMINER: INITIAL IF CITATION CONSIDERED, WHETHER OR NOT CITATION IS IN CONFORMANCE WITH MPEP 609; DRAW LINE THROUGH CITATION IF NOT
IN CONFORMANCE AND NOT CONSIDERED, INCLUDE COPY OF THIS FORM WITH NEXT COMMUNICATION TO APPLICANT.



28/28
PATENT

Case Docket No. ASMEX.320A
Date: October 16, 2003

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s) : Pomerade et al.
Appl. No. : 10/074,722
Filed : February 11, 2002
For : INTEGRATION OF HIGH K
GATE DIELECTRIC
Examiner : Ron Everett Pompey
Group Art Unit : 2812

I hereby certify that this correspondence and all marked attachments are being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on

October 16, 2003

(Date)

Joseph J. Mallon, Reg. No. 39,287

TRANSMITTAL LETTER

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Enclosed for filing in the above-identified application are:

- (X) An Information Disclosure Statement.
- (X) A PTO Form 1449 with seven (7) references.
- (X) The Commissioner is hereby authorized to charge any additional fees which may be required, or credit any overpayment, to Account No. 11-1410.
- (X) Return prepaid postcard.

Joseph J. Mallon
Registration No. 39,287
Attorney of Record
Customer No. 20,995
(619) 235-8550